

## Silicon Oxide-C Composite

Catlog Number: BMAM-0057

### • Description

High-capacity silicon oxide particles with a carbon-coated surface to improve electronic conductivity and buffer volume expansion during cycling.

### • Basic Information

Chemical Formula: SiO<sub>x</sub>/C

Appearance: Dark Grey Powder

D50 Particle Size: 4 - 8 μm

Tap Density: ≥ 0.9 g/cm<sup>3</sup>

BET Surface Area: 2.0 - 5.0 m<sup>2</sup>/g

1st Discharge Capacity: ≥ 1450 mAh/g

1st Coulombic Efficiency: ≥ 78%

Carbon Content: 5 - 10 wt%

Active Metal Content: Si: ~38%

Ash Content: ≤ 0.15%

Moisture Content: ≤ 0.10%

pH Value: 6.0 - 8.0

Iron (Fe) Impurity: ≤ 50 ppm

True Density: 2.2 - 2.3 g/cm<sup>3</sup>

Compaction Density: ≥ 1.4 g/cm<sup>3</sup>

Crystal Structure: Amorphous

Surface Coating: Carbon

Magnetic Impurities: ≤ 50 ppb

Electronic Conductivity: ~10<sup>-2</sup> S/cm

Voltage Range: 0.01 - 1.5 V

Purity: ≥ 99.5%

Primary Application: High-energy LIB

Thermal Stability: Moderate

Cycle Life: ≥ 600 cycles

 For Research or Industrial Raw Materials, Not For Personal Medical Use!